NSN 5961-01-226-3730

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-226-3730 **Inclosure Material:** Plastic **Overall Length:** 0.972 inches **Overall Height:** 0.110 inches Overall Width: 0.314 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 150.0 breakdown voltage, collector-to-base, emitter open and 150.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 1.50 amperes source cutoff current and 1.50 amperes source cutoff current **Power Rating Per Characteristic:** 1.2 watts small-signal input power, common-collector **Transfer Ratio:** 60.0 static forward current transfer ratio, common-emitter and 320.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: